

REMARKS

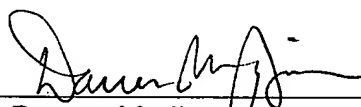
Prior to the examination of the above-identified application, please enter this Preliminary Amendment.

If there is any fee due in connection with the filing of this Preliminary Amendment, please charge the fee to our Deposit Account No. 06-0916.

Respectfully submitted,

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Dated: June 22, 2001

By: 
Darren M. Jiron
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APPENDIX

Attachment to the Preliminary Amendment filed on June 22, 2001.

Application Serial No.: 09/469,190

Attorney Docket No.: 04329.2210

Marked up version of amended claim:

18. (Amended) A semiconductor device according to claim 16, wherein the capacitor insulating film is one selected from the group consisting of SrTiO_3 , $(\text{Ba}, \text{Sr})\text{TiO}_3$, $[\text{RO},] \text{Ta}_2\text{O}_5$, and $\text{Pb}(\text{Zr}, \text{Ti})\text{O}_3$.

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